



BUK9K25-40E

Dual N-channel 40 V, 29 mΩ logic level MOSFET

10 December 2013

Product data sheet

1. General description

Dual logic level N-channel MOSFET in an LPAK56D (Dual Power-SO8) package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

2. Features and benefits

- Dual MOSFET
- Q101 Compliant
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True logic level gate with $V_{GS(th)}$ rating of greater than 0.5 V at 175 °C

3. Applications

- 12 V Automotive systems
- Motors, lamps and solenoid control
- Transmission control
- Ultra high performance power switching

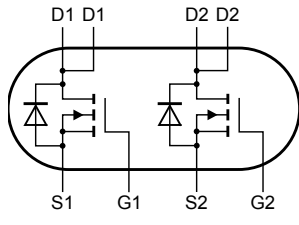
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25\text{ °C}$; $T_j \leq 175\text{ °C}$	-	-	40	V
I_D	drain current	$V_{GS} = 5\text{ V}$; $T_{mb} = 25\text{ °C}$; Fig. 1	-	-	18.2	A
P_{tot}	total power dissipation	$T_{mb} = 25\text{ °C}$; Fig. 2	-	-	32	W
Static characteristics FET1 and FET2						
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = 5\text{ V}$; $I_D = 5\text{ A}$; $T_j = 25\text{ °C}$; Fig. 11	-	24	29	mΩ
Dynamic characteristics FET1 and FET2						
Q_{GD}	gate-drain charge	$I_D = 5\text{ A}$; $V_{DS} = 32\text{ V}$; $V_{GS} = 5\text{ V}$; $T_j = 25\text{ °C}$; Fig. 13 ; Fig. 14	-	2.4	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source1	 LFPAK56D (SOT1205)	 mbk725
2	G1	gate1		
3	S2	source2		
4	G2	gate2		
5	D2	drain2		
6	D2	drain2		
7	D1	drain1		
8	D1	drain1		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BUK9K25-40E	LFPAK56D	Plastic single ended surface mounted package (LFPAK56D); 8 leads	SOT1205

7. Marking

Table 4. Marking codes

Type number	Marking code
BUK9K25-40E	92540E

8. Limiting values

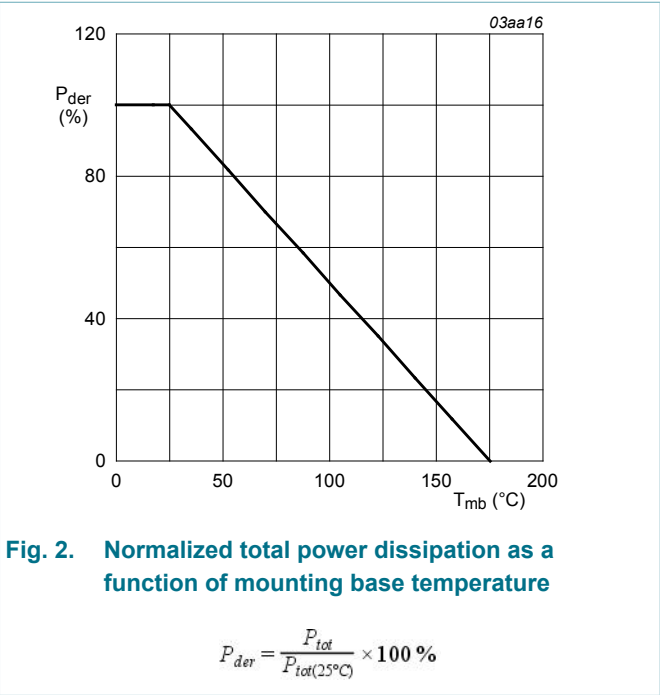
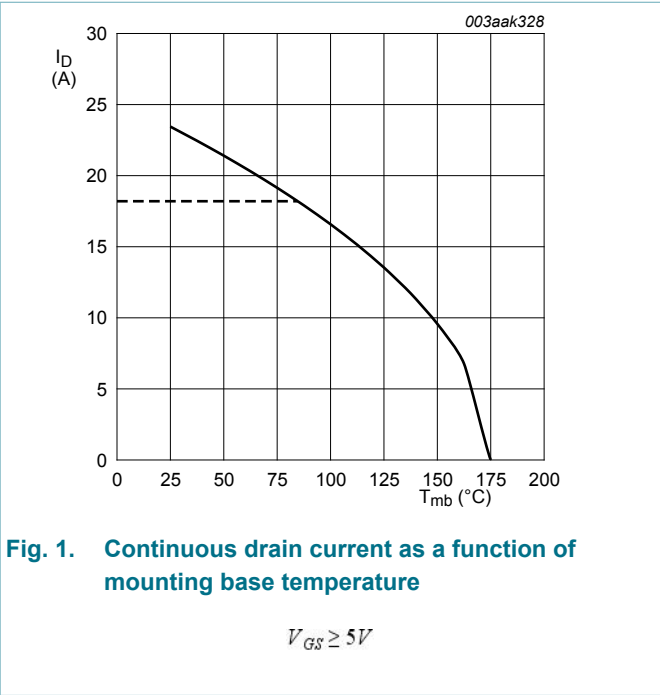
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25\text{ °C}$; $T_j \leq 175\text{ °C}$		-	40	V
V_{DGR}	drain-gate voltage	$R_{GS} = 20\text{ k}\Omega$		-	40	V
V_{GS}	gate-source voltage	$T_j \leq 175\text{ °C}$; Pulsed	[1][2]	-15	15	V
		$T_j \leq 175\text{ °C}$; DC		-10	10	V
I_D	drain current	$T_{mb} = 25\text{ °C}$; $V_{GS} = 5\text{ V}$; Fig. 1		-	18.2	A
		$T_{mb} = 100\text{ °C}$; $V_{GS} = 5\text{ V}$; Fig. 1		-	16.6	A
I_{DM}	peak drain current	$T_{mb} = 25\text{ °C}$; pulsed; $t_p \leq 10\text{ }\mu\text{s}$; Fig. 4		-	94	A

Symbol	Parameter	Conditions		Min	Max	Unit
P _{tot}	total power dissipation	T _{mb} = 25 °C; Fig. 2		-	32	W
T _{stg}	storage temperature			-55	175	°C
T _j	junction temperature			-55	175	°C
Source-drain diode FET1 and FET2						
I _S	source current	T _{mb} = 25 °C		-	18.2	A
I _{SM}	peak source current	pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C		-	94	A
Avalanche Ruggedness FET1 and FET2						
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	I _D = 18.2 A; V _{sup} ≤ 40 V; V _{GS} = 10 V; T _{j(init)} = 25 °C; Fig. 3	[3][4]	-	15	mJ

- [1] Accumulated Pulse duration up to 50 hours delivers zero defect ppm.
- [2] Significantly longer life times are achieved by lowering T_j and or V_{GS}.
- [3] Refer to application note AN10273 for further information
- [4] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C



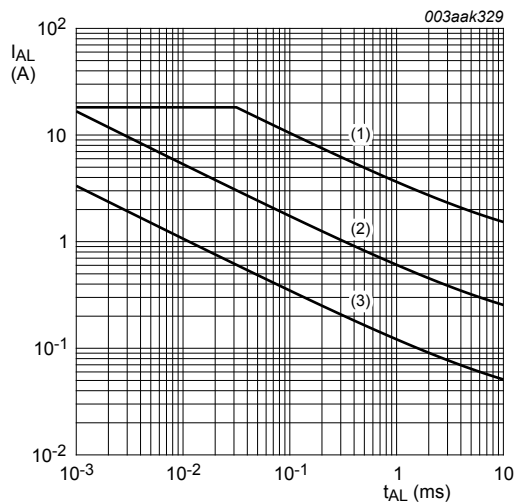


Fig. 3. Avalanche rating; avalanche current as a function of avalanche time

- (1) Single-pulse; $T_j = 25^\circ\text{C}$.
- (2) Single-pulse; $T_j = 150^\circ\text{C}$.
- (3) Repetitive.

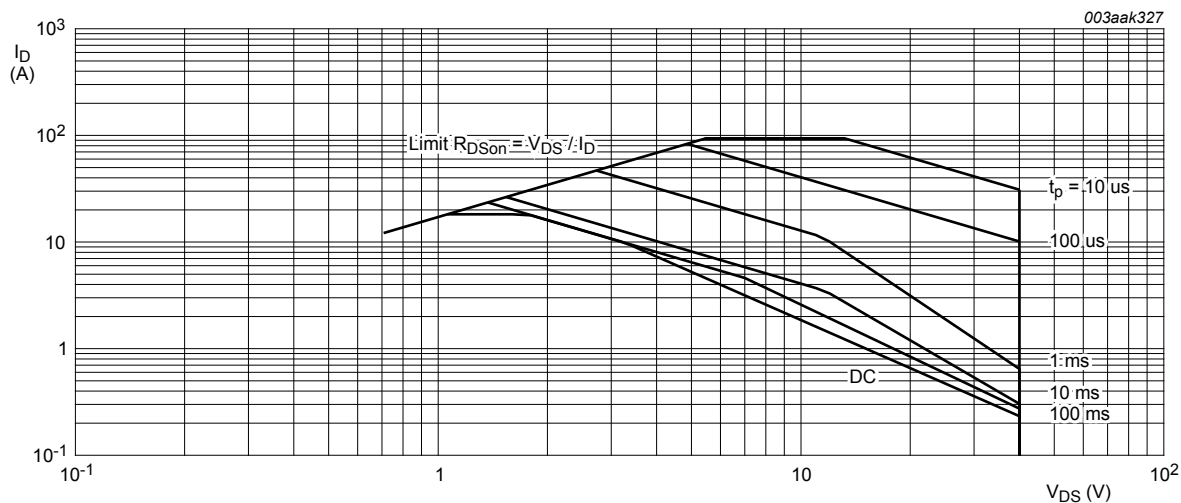


Fig. 4. Safe operating area; continuous and peak drain current as a function of drain-source voltage

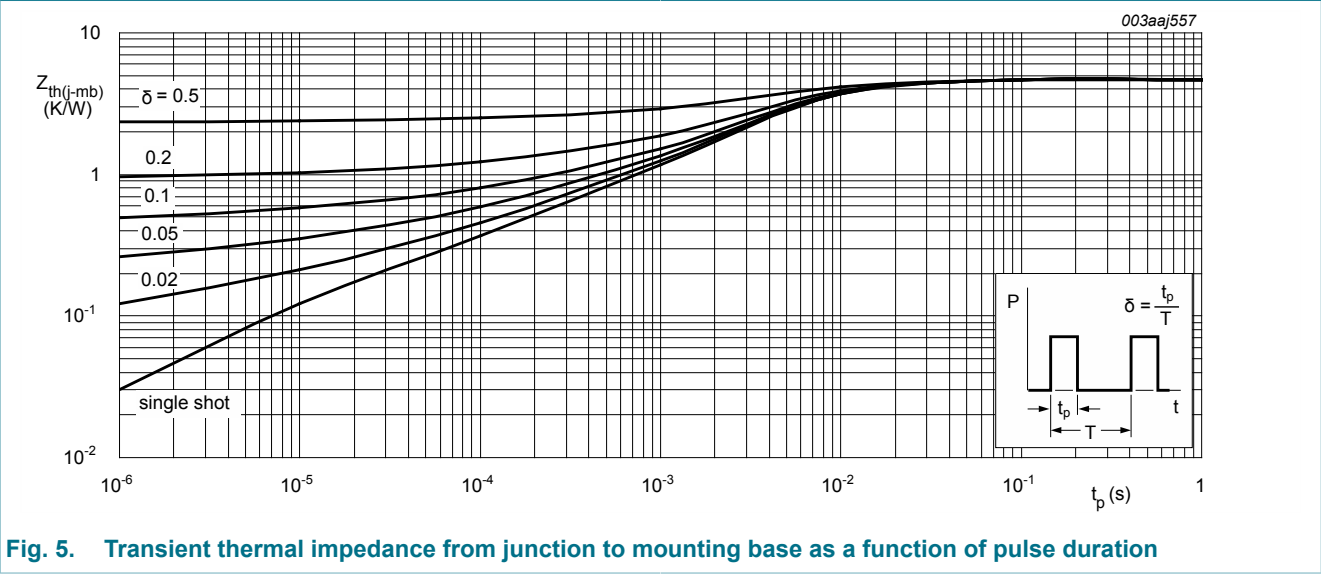
$T_{mb} = 25^\circ\text{C}; I_{DM}$ is single pulse

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5	-	-	4.68	K/W

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	Minimum footprint; mounted on a printed circuit board	-	95	-	K/W



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics FET1 and FET2						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250\text{ }\mu\text{A}$; $V_{GS} = 0\text{ V}$; $T_J = -55\text{ }^\circ\text{C}$	36	-	-	V
		$I_D = 250\text{ }\mu\text{A}$; $V_{GS} = 0\text{ V}$; $T_J = 25\text{ }^\circ\text{C}$	40	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1\text{ mA}$; $V_{DS} = V_{GS}$; $T_J = 25\text{ }^\circ\text{C}$; Fig. 9 ; Fig. 10	1.4	1.7	2.1	V
		$I_D = 1\text{ mA}$; $V_{DS} = V_{GS}$; $T_J = 175\text{ }^\circ\text{C}$; Fig. 9 ; Fig. 10	0.5	-	-	V
		$I_D = 1\text{ mA}$; $V_{DS} = V_{GS}$; $T_J = -55\text{ }^\circ\text{C}$; Fig. 9 ; Fig. 10	-	-	2.45	V
I_{DSS}	drain leakage current	$V_{DS} = 40\text{ V}$; $V_{GS} = 0\text{ V}$; $T_J = 175\text{ }^\circ\text{C}$	-	-	500	μA
		$V_{DS} = 40\text{ V}$; $V_{GS} = 0\text{ V}$; $T_J = 25\text{ }^\circ\text{C}$	-	0.02	1	μA
I_{GSS}	gate leakage current	$V_{GS} = -10\text{ V}$; $V_{DS} = 0\text{ V}$; $T_J = 25\text{ }^\circ\text{C}$	-	2	100	nA
		$V_{GS} = 10\text{ V}$; $V_{DS} = 0\text{ V}$; $T_J = 25\text{ }^\circ\text{C}$	-	2	100	nA
R_{DSon}	drain-source on-state resistance	$V_{GS} = 5\text{ V}$; $I_D = 5\text{ A}$; $T_J = 25\text{ }^\circ\text{C}$; Fig. 11	-	24	29	mΩ
		$V_{GS} = 5\text{ V}$; $I_D = 5\text{ A}$; $T_J = 175\text{ }^\circ\text{C}$; Fig. 11 ; Fig. 12	-	48.2	58	mΩ
		$V_{GS} = 10\text{ V}$; $I_D = 5\text{ A}$; $T_J = 25\text{ }^\circ\text{C}$; Fig. 11	-	19	24	mΩ

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Dynamic characteristics FET1 and FET2							
Q _{G(tot)}	total gate charge	I _D = 5 A; V _{DS} = 32 V; V _{GS} = 5 V; T _j = 25 °C; Fig. 13 ; Fig. 14		-	6.3	-	nC
Q _{GS}	gate-source charge			-	1.4	-	nC
Q _{GD}	gate-drain charge			-	2.4	-	nC
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 25 V; f = 1 MHz; T _j = 25 °C; Fig. 15		-	528	701	pF
C _{oss}	output capacitance			-	95	114	pF
C _{rss}	reverse transfer capacitance			-	56	76	pF
t _{d(on)}	turn-on delay time	V _{DS} = 32 V; R _L = 6.4 Ω; V _{GS} = 5 V; R _{G(ext)} = 5 Ω; T _j = 25 °C; I _D = 5 A		-	6.2	-	ns
t _r	rise time			-	9.2	-	ns
t _{d(off)}	turn-off delay time			-	10.8	-	ns
t _f	fall time			-	8.9	-	ns
Source-drain diode FET1 and FET2							
V _{SD}	source-drain voltage	I _S = 5 A; V _{GS} = 0 V; T _j = 25 °C; Fig. 16		-	0.83	1.2	V
t _{rr}	reverse recovery time	I _S = 5 A; dI _S /dt = -100 A/μs; V _{GS} = 0 V; V _{DS} = 20 V; T _j = 25 °C		-	15.9	-	ns
Q _r	recovered charge			-	7.6	-	nC

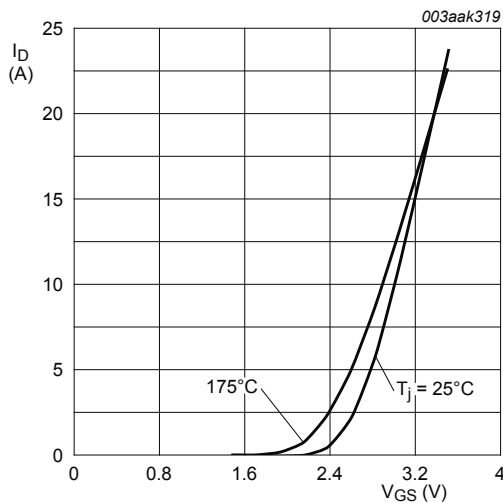


Fig. 6. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10 \text{ V}$$

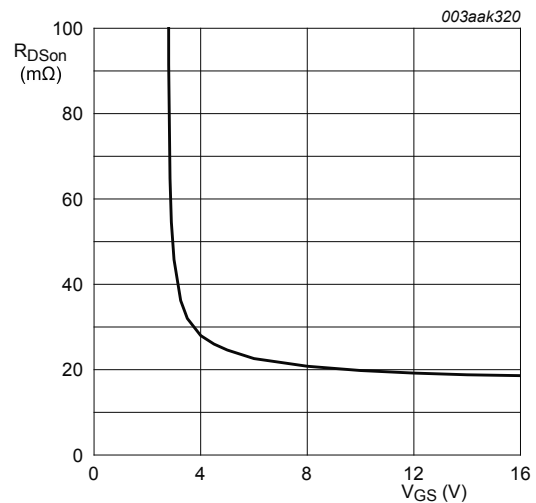
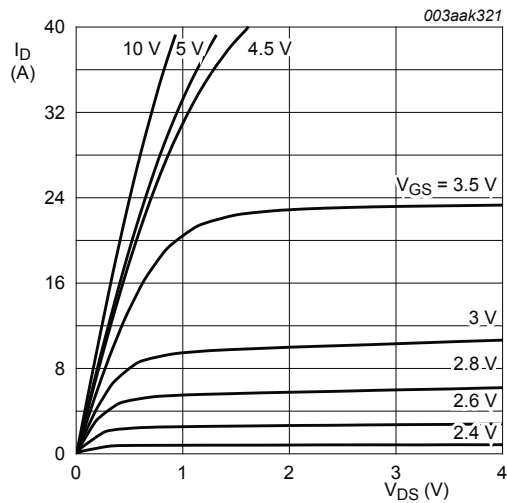


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_J = 25^\circ\text{C}; I_D = 5 \text{ A}$$



$T_j = 25\text{ }^{\circ}\text{C}$; $t_p = 300\text{ }\mu\text{s}$

Fig. 8. Output characteristics; drain current as a function of drain-source voltage; typical values

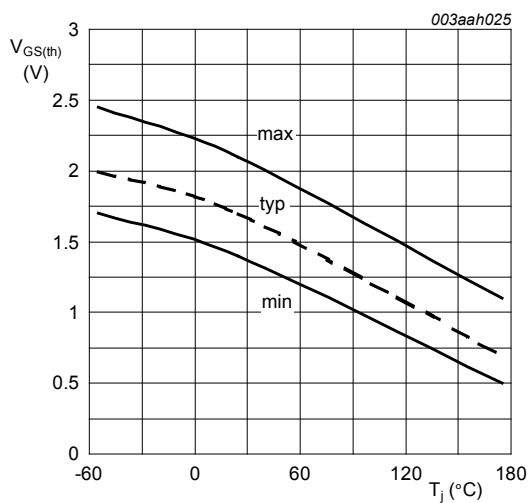


Fig. 9. Gate-source threshold voltage as a function of junction temperature

$I_D = 1\text{ mA}$; $V_{DS} = V_{GS}$

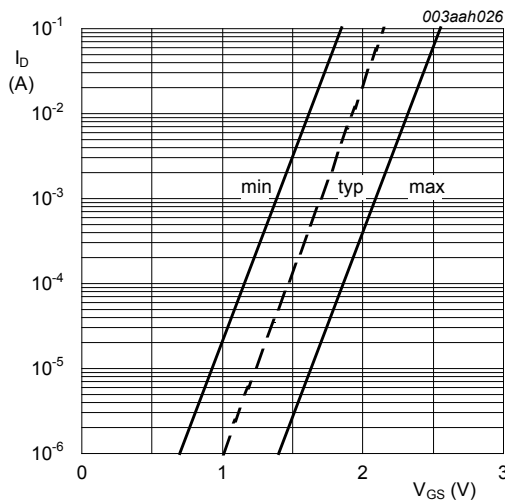
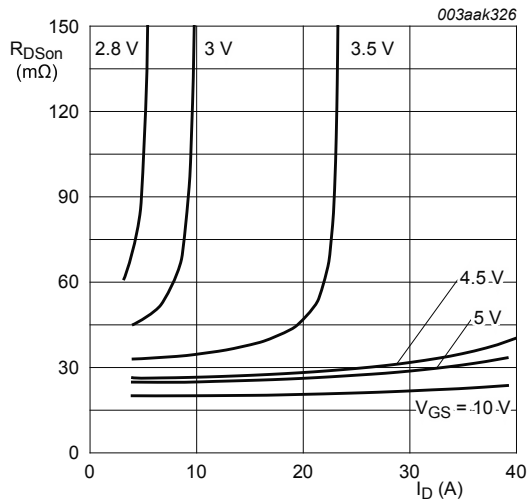


Fig. 10. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25\text{ }^{\circ}\text{C}$; $V_{DS} = 5\text{ V}$



$T_j = 25\text{ }^{\circ}\text{C}$; $t_p = 300\text{ }\mu\text{s}$

Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

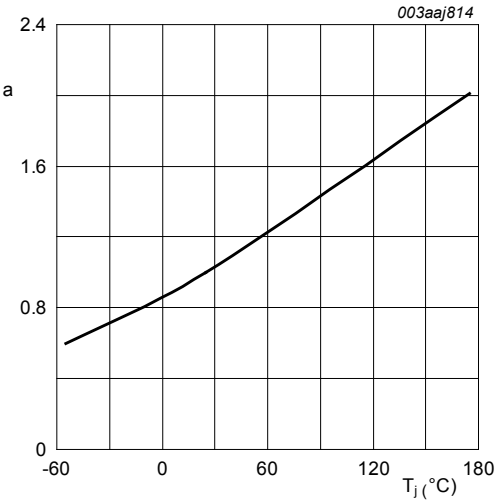


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DS(on)}}{R_{DS(on)}(25^\circ\text{C})}$$

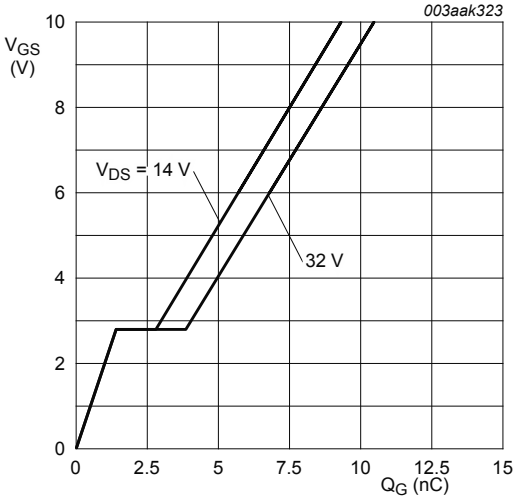


Fig. 13. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^\circ\text{C}; I_D = 5\text{ A}$$

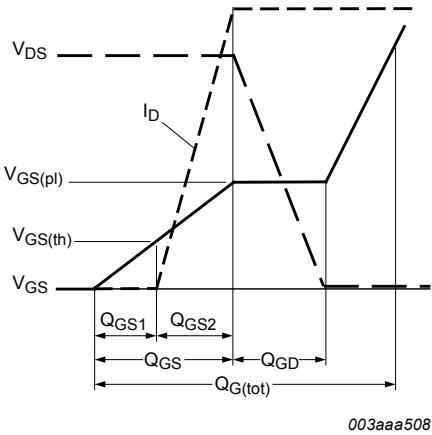


Fig. 14. Gate charge waveform definitions

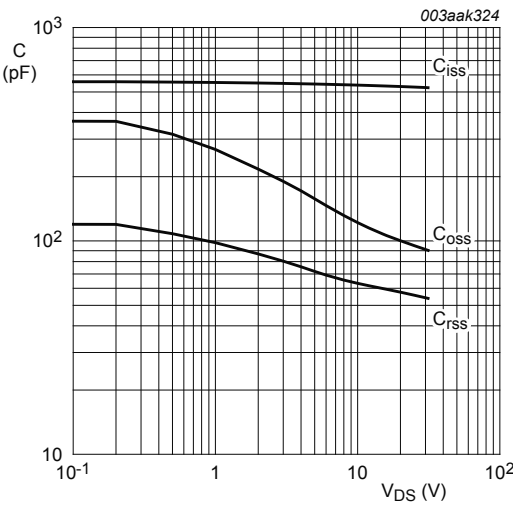


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = 0\text{ V}; f = 1\text{ MHz}$$

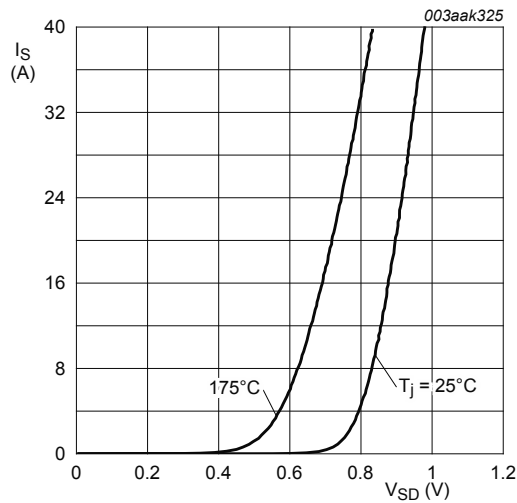


Fig. 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

$V_{GS} = 0V$

11. Package outline

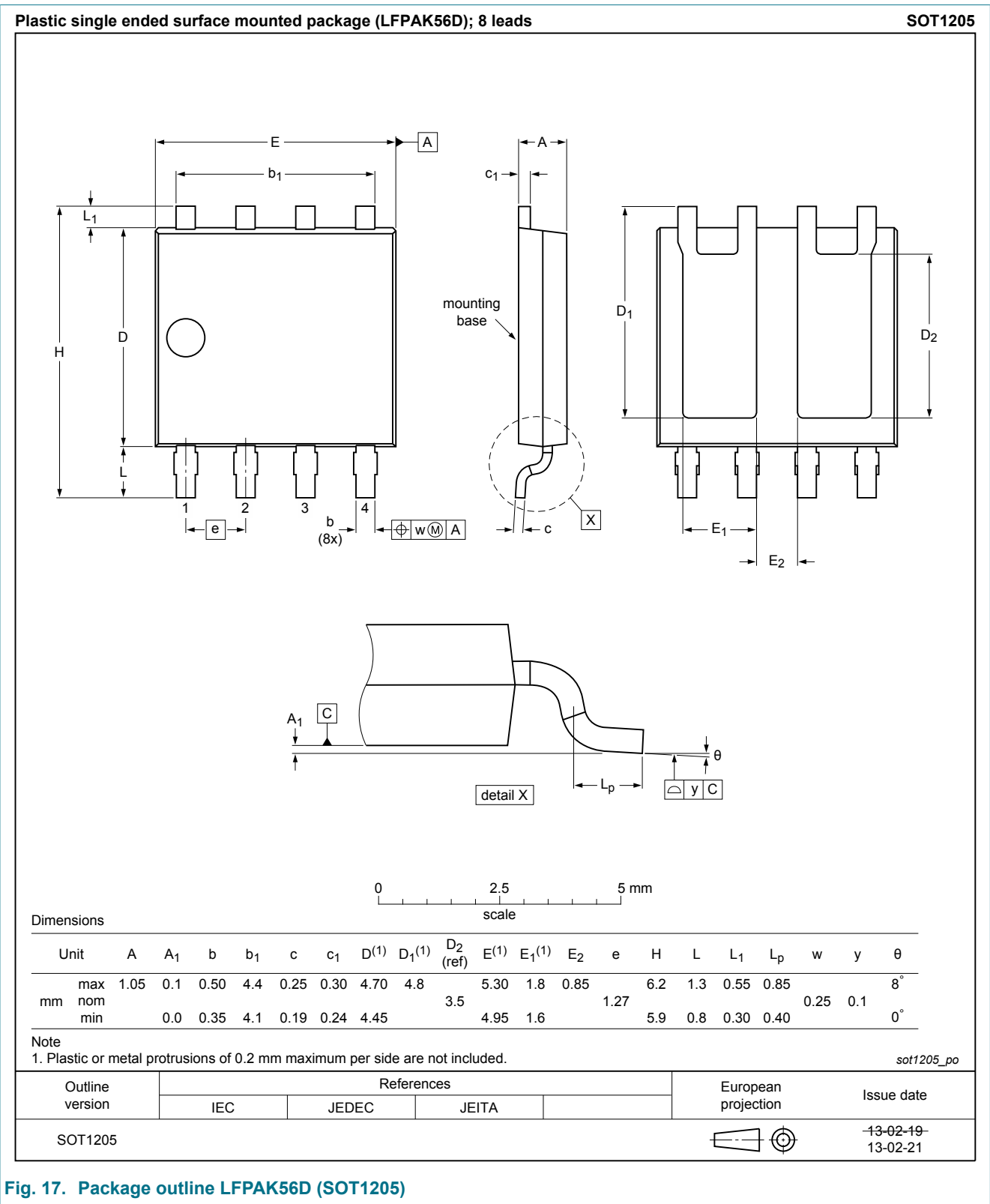


Fig. 17. Package outline LPAK56D (SOT1205)

12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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